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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Jia-Chong HO et al. Confirmation No: 2765
Appl. No. : 10/730,073
Filed : December 9, 2003
Title : COMPOUND SEMICONDUCTOR MATERIAL AND METHOD
FOR FORMING AN ACTIVE LAYER OF A THIN FILM
TRANSISTOR DEVICE

TC/A.U. : 2822
Examiner : T. Y. Tran

Docket No.: : HOJI3001/REF
Customer No: : 23364

AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

This is in response to the Official Action of May 19, 2005, in connection with the above-identified application. This response is timely filed.

Please amend the application as follows:

Amendments to the claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 4 of this paper.